B.Sc. ELECTRONICS SYLLABUS SCHEME OF INSTRUCTIONS

UNDER CBCS (w.e.f 2019-2020 academic year onwards)

Year	Semester	Title of the Paper [Theory and Practical]	Instructions Hrs/week	Number of Credits	Marks
1 st Year	I Sem	Paper – I: Circuit Analysis	4	4	100
		Practical – I: Circuit Analysis Lab	3	1	50
	II Sem	Paper – II: Electronic Devices	4	4	100
		Practical – II : Electronic Devices Lab	3	1	50
2 nd Year	III Sem	Paper – III: Analog Circuits	4	4	100
		Practical – III : Analog Circuits Lab	3	1	50
	IV Sem	Paper – IV: Linear Integrated circuits and Basics of Communication	4	4	100
		Practical – IV : Linear Integrated Circuits and Basics of Communication Lab	3	1	50
3 rd Year		Paper –V: Discipline Specific Elective - I A. Digital Electronics (OR) B. Microprocessor & Applications	4	4	100
	V Sem	Practical – V: Discipline Specific Elective - I A. Digital Electronics Lab (OR) B. Microprocessor Lab	3	1	50
		Paper – VI : Discipline Specific Elective - II A. Digital Communication (OR) B. Microcontroller & Applications	4	4	100
	VI Sem	Practical – VI: Discipline Specific Elective - II A. Digital Communication Lab (OR) B. Microcontroller Lab	3	1	50

Total Credits: 30

Skill enhancement courses:

- 1. Measurements and Errors
- 2. Basic Instrumentation
- 3. Biomedical Instrumentation
- 4. Hardware Definition Language

Generic Elective:

1. Basic Electronics

Project work (OR) Optional Paper (Digital System Design)

B.Sc. ELECTRONICS SYLLABUS
B.Sc. I YEAR Semester – I
DSC- Paper – I : Circuit Analysis

Total number of hours: 56
No of hours per week: 4

Credits: 4

UNIT - I

AC Fundamentals: The sine wave –average and RMS values – The J Operator – Polar and Rectangular forms of complex numbers – Phasor diagram-Complex impedance and admittance.

Kirchhoff's Current and Voltage Laws: Concept of Voltage and current sources-KVL and KCL- application to simple circuits (AC and DC) consisting of resistors and sources – Node voltage analysis and Mesh analysis.

<u>UNIT-II</u>

Network Theorems (DC and AC): Superposition Theorem ,Thevenin's Theorem, Norton's Theorem, Maximum power transfer Theorem, Reciprocity Theorem, Milliman's Theorem, Application to simple Networks.

<u>UNIT-III</u>

RC and RL Circuits: Transient Response of RL and RC Circuits with step input, Time constants. Frequency response of RC and RL circuits, Types of filters – Low pass filter and High pass filter- frequency response, passive differentiating circuit and passive integrating circuit.

UNIT-IV

Resonance: RLC Series and parallel resonance circuits –Resonant frequency –Q Factor- Bandwidth-Selectivity.

Cathode Ray Oscilloscope: Cathode Ray Tube (CRT) and its working, electron gun focusing, deflection sensitivity, florescent screen. Measurement of Time period, Frequency, Phase and amplitude.

Text Books:

- 1) Basic Electronics-Grob 10th edition(TMH)
- 2) Circuit Analysis-P.Gnanaswam pearson Education.
- 3) Circuit and Networks-A. Sudhakar & S. Pallri(TMH)
- 4) Pulse, digital & switching waveforms-Milliman &Taub.
- 5) Networks, Lines and Fields-John Ryder (PHI)
- 6) Network theory-Smarajit Ghosh(PHI)

B.Sc. I Year, Semester – I: Electronics Practical

Paper – I : Circuit Analysis Lab

No. of hours per week: 3

- 1. Measurement of peak voltage, frequency using CRO.
- 2. Measurement of phase using CRO.
- **3.** Thevenin's theorem and Norton's theorem verification.
- **4.** Maximum power transfer theorem verification.
- **5.** CR circuit Frequency response (Low pass and High pass).
- **6.** CR and LR circuits Differentiation and integration tracing of waveforms.
- **7.** LCR Series resonance circuit frequency response Determination of f_o , Q and band width.
- 8. Simulation: i) verification of KVL and KCL.
 - ii) study of network theorems.
 - iii) study of frequency response (LR).

Note: Student has to perform minimum of <u>Six</u> experiments.

Reference Books:

- 1) Lab manual for Electronic Devices and Circuits 4th Edition. By David A Bell PHI
- 2) Basic Electronics A Text Lab Manual –Zbar, Malvino, Miller.



B.Sc. ELECTRONICS SYLLABUS B.Sc. I YEAR Semester - II

DSC- Paper -II: Electronic Devices

Total number of hours : 56 No of hours per week: 4

Credits:4

UNIT- I

PN Junction: Formation of PN junction, Depletion region, Junction capacitance, Diode equation (no derivation) Effect of temperature on reverse saturation current, V - I characteristics and simple applications of i) Junction diode, ii) Zener diode, iii) Tunnel diode and iv) Varactor diode.

<u>UNIT-II</u>

Bipolar Junction Transistor(BJT) : PNP and NPN transistors, current components in BJT, BJT static characteristics (Input and Output) , Early effect , CB , CC , CE configurations of transistor and bias conditions (cut off, active, and saturation regions), CE configuration as two port network, h-parameter model and its equivalent circuit. Determination of <math>h-parameters from the characteristics. Load line analysis (AC and DC). Transistor Biasing – Fixed and self bias.

UNIT-III

Field Effect Transistor (FET): Construction and working of JFET, output and transfer characteristics of FET, Determination of FET parameters. Application of FET as Voltage variable resistor. Advantages of FET over BJT. **MOSFET**:: construction and working of enhancement and depletion modes, output and transfer characteristics Application of MOSFET as a switch.

Uni Junction Transistor (UJT): Construction and working of UJT and its Characteristics. Application of UJT as a relaxation oscillator.

UNIT- IV

Silicon Controlled Rectifier (SCR): Construction and working of SCR. Two transistor representation, Characteristics of SCR. Application of SCR for power control.

Photo electronic Devices: Construction and Characteristics of Light Dependent Resistor (LDR), Photo voltaic Cell, Photo diode, Photo transistor and Light Emitting Diode(LED).

Books Recommended:

- 1) Electronic Devices and circuits-Millman and Halkias, (TMH)
- 2) Principles of Electronics-V.K.Mehta & Rohit Mehta
- 3) Electronic Devices and Circuits-Allen Moltershed(PHI)
- 4) Basic Electronics and Linear Circuits-Bharghava U
- 5) Electronic Devices and Circuits-Y.N.Bapat
- 6) Electronic Devices and Circuits-Mithal.
- 7) Experiments in Electronics-S.V.Subramanyam.

B.Sc. I Year, Semester – II : Electronics Practical Paper – II : Electronic Devices Lab

No. of hours per week: 3

- 1. To draw volt- ampere characteristics of Junction diode and determine the cut in voltage, forward and reverse resistances.
- 2. Zener diode V I Characteristics Determination of Zener breakdown voltage.
- 3. Voltage regulator (line and load) using Zener diode.
- **4.** BJT input and output characteristics (CE configuration) and determination of 'h' parameters.
- **5.** FET Characteristics and determination of FET parameters.
- **6.** UJT characteristics determination of intrinsic standoff ratio.
- 7. UJT as relaxation oscillator.
- 8 Characteristics of LDR/Photo diode/Photo transistor/Solar cell.

Note: Student has to perform minimum of <u>Six</u> experiments.

Reference Books:

1) Lab manual for Electronic Devices and Circuits – 4th Edition. By David A Bell - PHI



Question paper pattern

Faculty of Science
Electronics
Title of the paper:
Paper:

Duration: 3Hrs] [Max. Marks: 80 **Section-A: Short Answer Questions** $(8 \times 4 = 32)$ **Answer any EIGHT questions** 1. Unit – I 2. Unit - I3. Unit – I (Problem) 4. Unit – II 5. Unit – II 6. Unit – II (Problem) 7. Unit – III 8. Unit – III 9. Unit – III (Problem) 10. Unit – IV 11. Unit – IV 12. Unit – IV (Problem) **Section B: Essay Answer Questions** $(4 \times 12 = 48)$ 13 (a) Unit – I OR (b) Unit – I 14 (a) Unit – II OR (b) Unit - II 15 (a) Unit – III OR (b) Unit – III

16 (a) Unit – IV OR (b) Unit – IV